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Vishay General Semiconductor

Dual High Voltage TMBS[®] (Trench MOS Barrier Schottky) Rectifier

Ultra Low $V_F = 0.43$ V at $I_F = 5$ A

FEATURES

- Trench MOS Schottky technology
- Low forward voltage drop, low power losses
- High efficiency operation
- Solder bath temperature 275 °C maximum, 10 s, per JESD 22-B106
- Material categorization: for definitions of compliance please see <u>www.vishay.com/doc?99912</u>

TYPICAL APPLICATIONS

For use in high frequency converters, switching power supplies, freewheeling diodes, OR-ing diode, DC/DC converters, and reverse battery protection.

MECHANICAL DATA

Case: TO-220AB

Molding compound meets UL 94 V-0 flammability rating Base P/N-M3 - halogen-free, RoHS-compliant, and commercial grade

Terminals: matte tin plated leads, solderable per J-STD-002 and JESD 22-B102

M3 suffix meets JESD 201 class 1A whisker test

Polarity: as marked

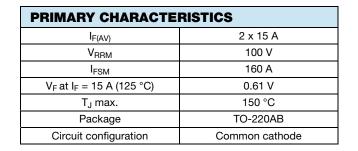
Mounting Torque: 10 in-lbs maximum

| MAXIMUM RATINGS (T _A = 25 °C unless otherwise noted) | | | | | |
|---|------------|-------------------------------|-------------|------|--|
| PARAMETER | | SYMBOL | V31103C | UNIT | |
| Maximum repetitive peak reverse voltage | | V _{RRM} | 100 | V | |
| Maximum average forward rectified current (fig. 1) | per device | 1 | 30 | A | |
| | per diode | IF(AV) | 15 | | |
| Peak forward surge current 8.3 ms single half sine-wave superimposed on rated load per diode | | I _{FSM} | 160 | А | |
| Operating junction temperature range | | T _J ⁽¹⁾ | -40 to +150 | ℃ | |
| Storage temperature range | | T _{STG} | -55 to +150 | U | |

Note

 $^{(1)}$ The heat generated must be less than the thermal conductivity from junction to ambient: dP_D/dT_J <1/ $R_{\theta JA}$









ROHS COMPLIANT



V31103C

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| ELECTRICAL CHARACTERISTICS ($T_J = 25 \text{ °C}$ unless otherwise noted) | | | | | | |
|---|------------------------|-------------------------|-------------------------------|-------|------|------|
| PARAMETER | TEST CO | NDITIONS | SYMBOL | TYP. | MAX. | UNIT |
| Instantaneous forward voltage | I _F = 5 A | T _J = 25 °C | V _F ⁽¹⁾ | 0.50 | - | - V |
| | I _F = 7.5 A | | | 0.55 | - | |
| | I _F = 15 A | | | 0.68 | 0.73 | |
| | I _F = 5 A | T _J = 125 °C | | 0.43 | - | |
| | I _F = 7.5 A | | | 0.49 | - | |
| | I _F = 15 A | | | 0.61 | 0.66 | |
| Reverse current at rated V _R per diode | V 70.V | T _J = 25 °C | I _R (2) | 0.012 | - | - mA |
| | V _R = 70 V | T _J = 125 °C | | 6.5 | - | |
| | V _R = 100 V | T _J = 25 °C | | - | 0.9 | |
| | | T _J = 125 °C | | 16.0 | 35 | |
| Typical junction capacitance | 4 V, 1MHz | - | CJ | 1600 | - | pF |

Notes

 $^{(1)}\,$ Pulse test: 300 μs pulse width, 1 % duty cycle

⁽²⁾ Pulse test: Pulse width \leq 5 ms

| THERMAL CHARACTERISTICS ($T_A = 25 \text{ °C}$ unless otherwise noted) | | | | | |
|--|---------------------------------|---------|------|--|--|
| PARAMETER | SYMBOL | V31103C | UNIT | | |
| Typical thermal resistance per device | R _{0JC} ⁽¹⁾ | 1.0 | °C/W | | |

Note

⁽¹⁾ Thermal resistance junction-to-case to follow JEDEC[®] 51-14 transient dual interface test method (TDIM)

| ORDERING INFORMATION (Example) | | | | | | |
|--------------------------------|-----------------|--------------|---------------|---------------|--|--|
| PREFERRED P/N | UNIT WEIGHT (g) | PACKAGE CODE | BASE QUANTITY | DELIVERY MODE | | |
| V31103C-M3/P | 1.88 | Р | 50/tube | Tube | | |



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RATINGS AND CHARACTERISTICS CURVES ($T_A = 25$ °C unless otherwise noted)

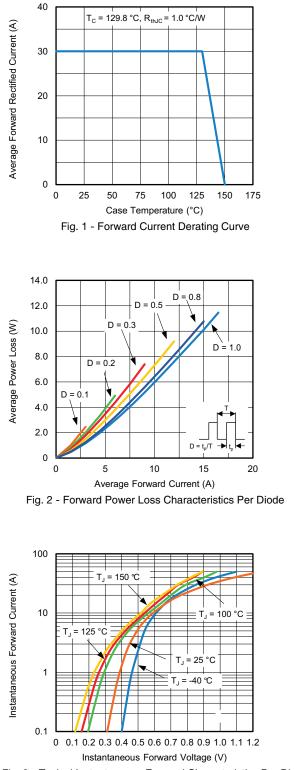
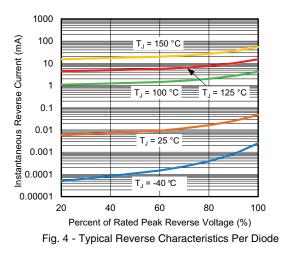
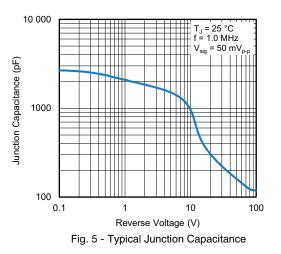
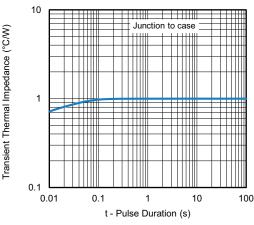
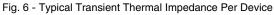


Fig. 3 - Typical Instantaneous Forward Characteristics Per Diode









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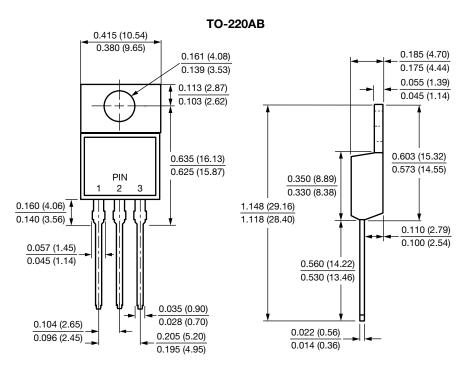
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PACKAGE OUTLINE DIMENSIONS in inches (millimeters)





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